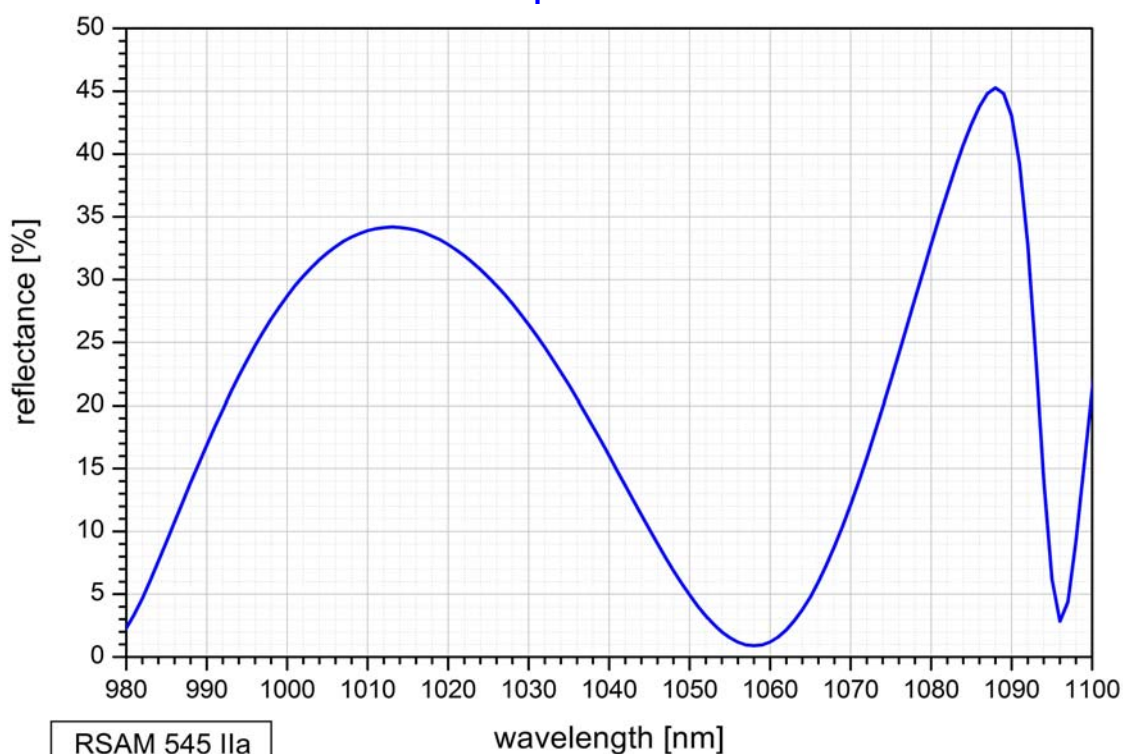


RSAM data sheet RSAM-1060-x, $\lambda = 1060 \text{ nm}$

RSAM - Resonant saturable absorber mirror

Working wavelength	$\lambda = 1050 \dots 1064 \text{ nm}$ (angle and temperature dependent)
Full Width at Half Maximum	FWHM = 40 nm
Low intensity absorptance	$A \geq 99 \%$
Low intensity reflectance	$R_{\min} \leq 1 \%$
Saturation fluence	$\Phi_{\text{sat}} = 121 \mu\text{J}/\text{cm}^2$
Relaxation time constant	$\tau \sim 3 \text{ ps}$
Non-saturable loss	$A_{\text{ns}} = 45 \%$
Chip area	4mm x 4mm; other dimensions on request
Chip thickness	400 μm
Front side	dielectric cover
Mounting of RSAM-1060-x	denotes the type of mounting as follows:
x = 0	unmounted
x = 12.7 g	glued on a gold plated Cu-cylinder with 12.7 mm \varnothing
x = 25.4 g	glued on a gold plated Cu-cylinder with 25.4 mm \varnothing
x = 12.7 s	soldered on a gold plated Cu-cylinder with 12.7 mm \varnothing
x = 25.4 s	soldered on a gold plated Cu-cylinder with 25.4 mm \varnothing
x = 25.0 w	soldered on a water cooled Cu-cylinder with 25.0 mm \varnothing
x = FC	mounted on a 1 m monomode fiber cable with FC/PC connector
x = FC/PC with TEC	mounted on a 1 m monomode fiber cable with FC/PC or other connector type and TEC (thermoelectric cooler) for fine tuning of the resonance wavelength

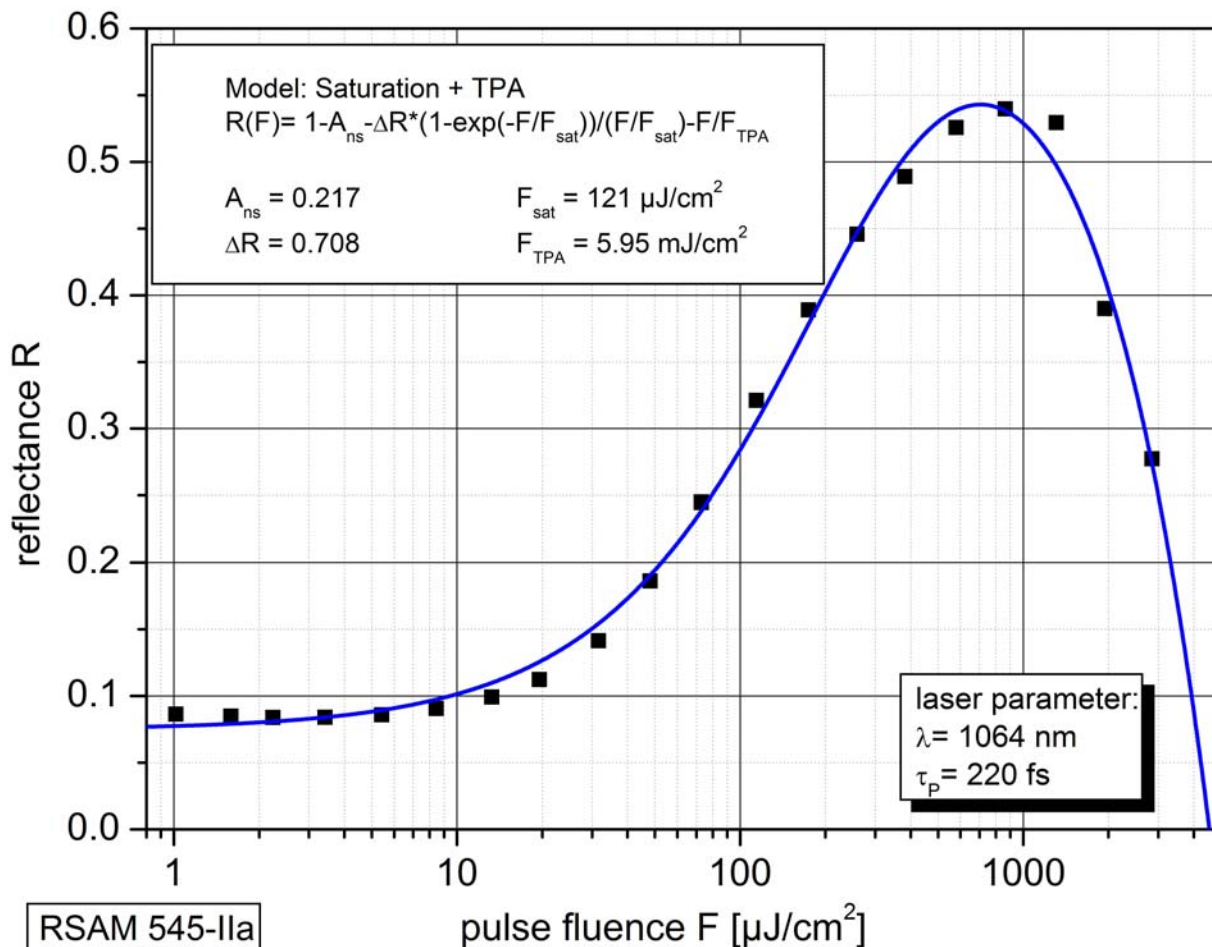
Unsaturated spectral reflectance



RSAM 545 IIa

wavelength [nm]

Saturation measurement at 1064 nm



Pump-probe measurement at 1064 nm on a sample from the same wafer, but with another dielectric coating

